





EMVA13 A A 2 -4.032M TR

Series

RoHS Compliant (Pb-free) 4 Pad 5mm x 7mm SMD

3.3Vdc LVCMOS Voltage Controlled MEMS Oscillator

Frequency Tolerance/Stability – ±50ppm Maximum

Operating Temperature Range – -20°C to +70°C

Packaging Options
Tape & Reel
Nominal Frequency

Absolute Pull Range ±50ppm Minimum

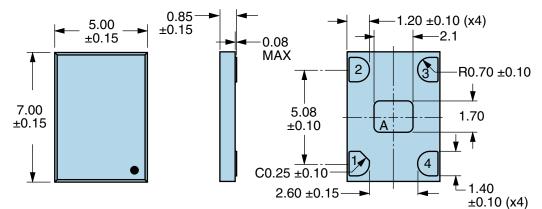
ELECTRICAL SPECIFICA	ELECTRICAL SPECIFICATIONS		
Nominal Frequency	4.032MHz		
Frequency Tolerance/Stability	±50ppm Maximum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration)		
Aging at 25°C	±1ppm Maximum First Year		
Operating Temperature Range	-20°C to +70°C		
Supply Voltage	3.3Vdc ±10%		
Input Current	15mA Maximum		
Output Voltage Logic High (Voh)	90% of Vdd Minimum (IOH = -4mA)		
Output Voltage Logic Low (Vol)	10% of Vdd Maximum (IOL = +4mA)		
Rise/Fall Time	2nSec Maximum (Measured from 20% to 80% of waveform)		
Duty Cycle	50 ±5(%) (Measured at 50% of waveform)		
Load Drive Capability	15pF Maximum		
Output Logic Type	CMOS		
Absolute Pull Range	±50ppm Minimum (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, Shock, Vibration, and First Year Aging at 25°C over the Control Voltage (Vc).)		
Control Voltage	0.05Vdc to 1.7Vdc (Test Condition for APR)		
Control Voltage Range	0.0Vdc to 1.8Vdc		
Linearity	1% Maximum		
Transfer Function	Positive Transfer Characteristic		
Modulation Bandwidth	8kHz Typical, 5kHz Minimum (Measured at -3dB, Vc = 0.875Vdc)		
Input Impedance	250kOhms Minimum		
Input Leakage Current	10μA Maximum		
Typical Phase Noise at Offsets	-100dBc/Hz at offset of 10kHz, -115dBc/Hz at offset of 100kHz, -145dBc/Hz at offset of 1MHz, and -154dBc/Hz at offset of 10MHz		
Period Jitter (RMS)	3pSec Typical, 6pSec Maximum		
Period Jitter (pk-pk)	20pSec Typical, 40pSec Maximum		
RMS Phase Jitter (Fj = 1.875MHz to 20MHz; Random)	0.8pSec Typical		
RMS Phase Jitter (Fj = 900kHz to 7.5MHz; Random)	0.6pSec Typical		
Start Up Time	10mSec Maximum		
Storage Temperature Range	-55°C to +125°C		

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
ESD Susceptibility	MIL-STD-883, Method 3015, Class 2, HBM 2000V	
Flammability	UL94-V0	
Mechanical Shock	MIL-STD-883, Method 2002, Condition G, 30,000G	
Moisture Resistance	MIL-STD-883, Method 1004	
Moisture Sensitivity Level	J-STD-020, MSL 1	
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003 (Four I/O Pads on bottom of package only)	



ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
Temperature Cycling	MIL-STD-883, Method 1010, Condition B	
Thermal Shock	MIL-STD-883, Method 1011, Condition B	
Vibration	MIL-STD-883, Method 2007, Condition A, 20G	

MECHANICAL DIMENSIONS (all dimensions in millimeters)



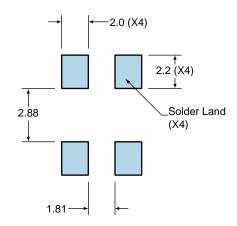
Note A: Center paddle is connected internally to oscillator ground (Pad 2).

PIN CONNECTION 1 Control Voltage 2 Case Ground 3 Output 4 Supply Voltage

LINE	MARKING
1	XXXX or XXXXX XXXX or XXXXX=Ecliptek Manufacturing Lot Code

Suggested Solder Pad Layout

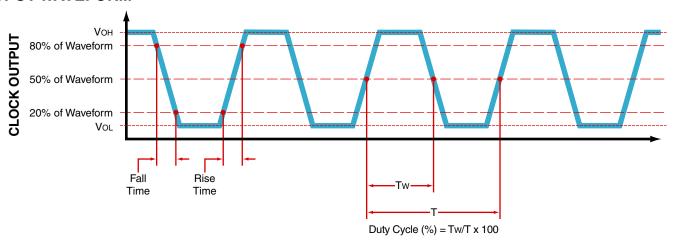
All Dimensions in Millimeters



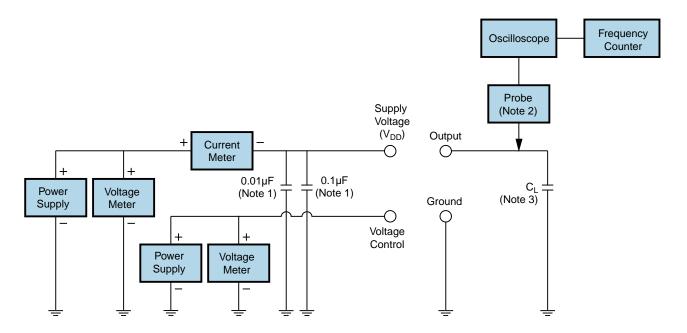
All Tolerances are ±0.1



OUTPUT WAVEFORM



Test Circuit for CMOS Output

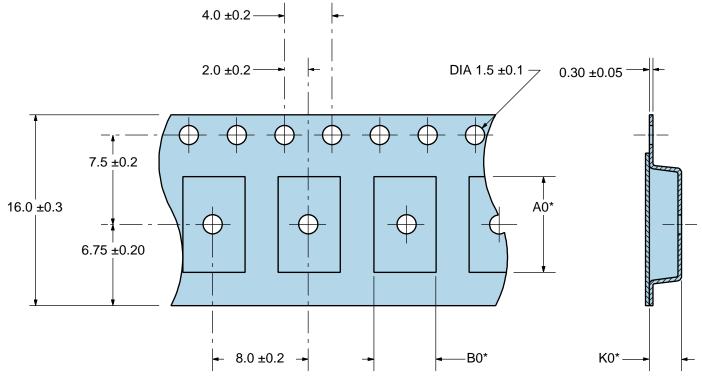


- Note 1: An external $0.1\mu\text{F}$ low frequency tantalum bypass capacitor in parallel with a $0.01\mu\text{F}$ high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value C₁ includes sum of all probe and fixture capacitance.

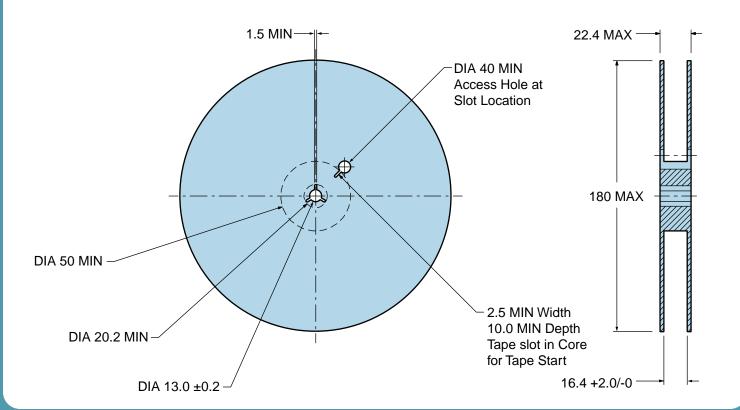


Tape & Reel Dimensions

Quantity Per Reel: 1,000 units



*Compliant to EIA 481A





Recommended Solder Reflow Methods



High Temperature Infrared/Convection

T _s MAX to T _∟ (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	150°C
- Temperature Typical (T _s TYP)	175°C
- Temperature Maximum (T _S MAX)	200°C
- Time (t _s MIN)	60 - 180 Seconds
Ramp-up Rate (T _L to T _P)	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T _P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T _P Target)	250°C +0/-5°C
Time within 5°C of actual peak (t _p)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

T _S MAX to T _L (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T _s MIN)	N/A
- Temperature Typical (T _s TYP)	150°C
- Temperature Maximum (T _s MAX)	N/A
- Time (t _s MIN)	60 - 120 Seconds
Ramp-up Rate (T _L to T _P)	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T _P)	240°C Maximum
Target Peak Temperature (T _P Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (tp)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.